Competition between Spin-Orbit Interaction and Zeem an Coupling in Rashba 2DEGs

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We investigate system atically how the interplay between R ashba spin-orbit interaction and Zeeman coupling a ects the electron transport and the spin dynamics in InG aA s-based 2D electron gases. From the quantitative analysis of the magnetoconductance, measured in the presence of an in-plane magnetic eld, we conclude that this interplay results in a spin-induced breaking of time reversal symmetry and in an enhancement of the spin relaxation time. Both e ects, due to a partial alignment of the electron spin along the applied magnetic eld, are found to be in excellent agreement with recent theoretical predictions.

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A chieving control of the orbitalm otion of electrons by acting on their spin is a key concept in modem spintronics and is at the basis of many proposals in the eld of quantum information [1]. Two physical mechanisms are used to in uence the dynamics of the electron spin in normal conductors: spin-orbit interaction (SO I) and Zeem an coupling. In the presence of elastic scattering, these two mechanisms a ect the spin in di erent ways. SO I is responsible for the random ization of the spin direction whereas the Zeem an coupling tends to align the spin along the applied magnetic eld. Depending on the relative strength of these interactions, this interplay of SO I and Zeem an coupling is responsible for the occurrence of a variety of physical phenom ena [2, 3].

Q uantum wells (QW) that de ne 2-dimensional electron gases (2DEGs) are particularly suitable for the experimental investigation of the competition between SOI and Zeem an coupling, since they give control over m any of the relevant physical parameters. Specifically, in these systems the SOI strength can be controlled by an appropriate QW design [4] and by applying a voltage to a gate electrode [5]. The electron m obility is usually density dependent, so that the elastic scattering time can also be tuned by acting on the gate. Finally, Zeem an coupling to the orbital motion of the electrons by applying a magnetic eld parallel to the conduction plane.

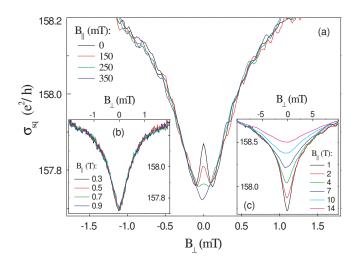
In this Letter we study the competition of SO I and Zeem an coupling via magnetoconductance measurements in InG aA shased 2D EGs with di erent Rashba SO I strength. From the detailed quantitative analysis of the weak antilocalization as a function of an applied in-plane magnetic eld (B_k), we not that the partial alignment of the spin along B_k results in a spin-induced time reversal symmetry (TRS) breaking, and in an increase of the spin relaxation time. The increase in spin relaxation time is found to be quadratic with B_k , and strongly dependent on the SO I strength and the elastic scattering time. For both the spin-induced TRS breaking and the increase in spin relaxation time we nd excellent quantitative agreement with recent theory. We also show that the quantitative analysis permits to determ ine the in-plane g-factor of the electrons.

The three InA IA s/InG aA s/InA IA s quantum wells used in our work are very similar to those described in detail elsewhere[4]. Here, we recall that each well is designed to have a di erent (Rashba) SO I strength. The characteristic spin-split energy for the di erent sam ples is

0:5;15 and 1:8m eV (in what follows we will refer to these samples as to samples 1, 2, and 3, respectively). The electron density and mobility at $V_{gate} = 0V$ are n' 7 1¹⁰m² and ' 4m²=V s. A llm easurements have been performed on (20 x 80 m) Hall-bar shaped devices, at 1.6K .A 14 T superconducting magnet is used to generate B_k and homermade split coils mounted on the sample holder are used to independently control the perpendicular eld (B_2). No signi cant di erence in the results is observed when the in-plane eld is applied parallel or perpendicular to the direction of current ow.

To understand how an in-plane magnetic eld a ects the electronic transport, we rst discuss the behavior of sample 1 with the weakest SO I strength. Figure 1 shows the magnetoconductance of this sample measured as a function of B₂ [7], for dierent xed values of the inplane eld B_k. For small values of B_k (main panel), the conductance exhibits a maximum at B₂ = 0, due to weak-antilocalization (W AL) superim posed on the background of weak-localization (W L) [8]. As B_k is increased, the amplitude of thism aximum is reduced and eventually disappears around B_k = 300m T. A further increase in B_k does not result in additional changes of the magnetoconductance until B_k reaches approximately 1T (g.lb). U pon increasing B_k even further, the W L signal is also suppressed on the scale of several (' 10) Tesla (g.lc).

These observations allow us to conclude that the suppression of W A L and of W L in a parallel eld are due



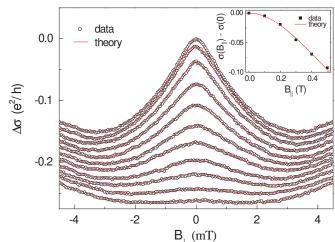


FIG.1: Them agnetoconductance (B $_{?}$) of sam ple1 at di erent values of B $_{k}$. Three regim es can be identi ed: increasing B $_{k}$ from 0 to 350m T results in a suppression of the W A L peak (a), increasing B $_{k}$ further (up to about B $_{k}$ = 1T) does not induce additional changes in the (B $_{?}$)-curves (b), for values of B $_{k}$ larger than 1T the W L is suppressed (c).

FIG.2: The empty circles are the measured magnetoconductance = (B₂) (0) of sample 2 at dimensional values of B_k (o set for clarity). B_k is increased from 0 to 1T, in steps of 0:1T (top to bottom). The solid lines represent best to the ILP theory. The inset shows the amplitude of the WAL peak at B₂ = 0 as function of B_k, i.e. (B₂ = 0; B_k) (0; 0), and the best t to the theory (solid line).

to two distinct mechanisms causing time reversal symmetry breaking. At large elds, $B_k = 1T$, $W \perp$ (which is not sensitive to the spin degree of freedom) is suppressed due to TRS breaking caused by the coupling of B_k to the orbital motion of the electrons, owing to the nite thickness of the quantum well and the asymmetric conning potential [9]. The suppression of the WAL peak at smaller values of B_k originates from a spin-induced TRS breaking due to the interplay between B_k (Zeem an coupling) and SO I, as predicted theoretically [10]. In this paper we will focus on the spin mechanism for TRS, and discuss the orbital mechanism elsewhere.

The complete separation of spin and orbital TRS breaking, which is essential for the work presented here, has not been previously reported [3]. In our sam ples, this separation is due to the small QW thickness (10nm) and the small e ective mass (m $0:041m_0$) which make the subband splitting in the QW relatively large, as well as to the relatively large gyrom agnetic ratio (g ' 3) [9, 10]. It allows us to account for the magneto conductance curves (B $_{?}$) measured at B $_{k}$ < 1T in term s of existing theories that only consider the coupling of B_k to the electron spin. Therefore, the number of param eters that need to be introduced for the quantitative analysis of the data is the sm allest possible. This makes it possible to extract the values of the phase coherence time and the spin relaxation time as a function of B_k with great accuracy, as it is needed to observe the dependence of s on the in-plane magnetic eld.

W e have perform ed a quantitative analysis of the m agnetoconductance curves on all samples and for di erent values of n, by thing the (B $_2$) curves with the theory of

Iordanskii, Lyanda-Geller and Pikus (ILP) [11, 12]. This is appropriate for our samples, in which the spin relaxation is governed by the D yakonov-Perelm echanism [13]. From this analysis, namely from the ts of (B $_{
m 2}$) curves measured at di erent values of the in-plane eld, we nd the B_k -dependence of s and , i.e. s (B_k) and (B_k) [14]. It is worth noting that in the ILP theory only one param eter is needed to account for the spin relaxation, $_{\rm S_x}$ (0) = $_{\rm S_y}$ (0) = 2 $_{\rm S_z}$ (0). In the pres $since_{s}(0)$ ence of an in-plane eld, how ever, these relations may not hold, since relaxing the spin along B_k costs energy (g B_k) whereas relaxation in the direction perpendicular to B_k does not. Nevertheless, for su ciently sm all B_k (g $B_k < kT$), the ratios between the di erent relaxation times are expected to change only minorly under the conditions of our experim ents. This allow sus to treat $_{\rm s}$ (B $_{\rm k}$) as a single thing parameter.

Figure 2a displays the results of the tting procedure on sample 2 with the interm ediate SOI strength. The continuous lines superim posed on the data represent the best t to the ILP theory, and show that the agreem ent between data and theory is excellent for all values of B_k . Sim ilar agreem ent is obtained for the other sam ples and for all the di erent values of the electron density n. The values of (B_k) and (B_k) , as extracted from the ts, are shown in Figs. 3 and 4. Note that, since the electron mobility depends on the density, we are able to investigate how changing the elastic scattera ects the B $_{\rm k}$ -dependence of the phase coherence ing and of the spin-relaxation time. This is of particular interest as both (B_k) and (B_k) are predicted to de-

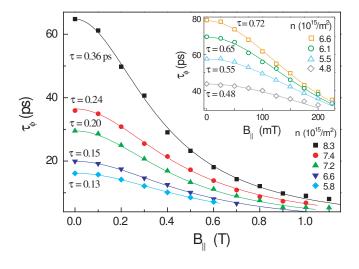


FIG.3: The sym bols represent as a function of B_k , as extracted from the analysis of the magnetoconductance of sample 2, using the LP theory (see Fig. 2). D i erent curves correspond to di erent values of n (and elastic scattering time). The solid lines are best to based on the theory describing spin-induced dephasing [10]. The decrease of with decreasing electron density is consistent with dephasing originating from electron-electron interaction. The inset shows the extracted (B_k) and theoretical to for sample 1.

pend on the Dyakonov-Perel spin relaxation time $_{\rm s}$ (0) (see Eqs. 2 and 3), which is related to by the relation $1 = _{\rm s}$ (0) = $^2 = 2h^2$ [11].

For all values of n, the measured (B_k) decreases as a function of B_k (Fig. 3), which shows quantitatively the breaking of TRS due to the interplay of Zeem an coupling and SO I. This interplay is predicted to result in a quadratic dependence of on B_k [10]:

$$\frac{(B_k)}{(0)} = \frac{1}{1 + cB_k^2}$$
(1)

where c is a constant given by:

$$c = (0)_{s} (0) (g_{k}_{B} = h)^{2}$$
 (2)

and g_k is the in-plane g-factor. The solid lines in Fig. 3 are best to the data using Eq. (1) and treating c as a (density dependent) thing parameter. Also in this case the agreement between experiment and theory is excellent for all values of n and for the dimentian ples (the inset of Fig. 3 shows the behavior of sample 1. Equally good agreement is found for sample 3).

U sing the value of c obtained from thing the data of Fig. 3 we directly obtain g_k (Eq. 2). We nd that, for each sample, the in-plane g-factor is approximately constant as a function of the electron density. The absolute values are determined to be $jg_k j = 2.8$ 0.1, $jg_k j = 3.3$ 0.1 and jg j = 3.5 0.1, for samples 1, 2 and 3,

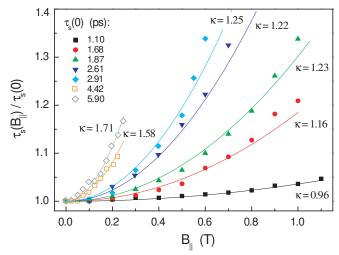


FIG. 4: The symbols represent $_{\rm S}$ as function of B_k, as extracted from the analysis of the magnetoconductance of sam – ple 1 (open symbols) and sam ple 2 (lled symbols). Each set of symbols corresponds to a di erent value of the D yakonov–Perel spin-relaxation time $_{\rm S}$ (0), with $1 = _{\rm S}$ (0) = $^2 = 2h^2$ (controlled by changing the gate voltage). The solid lines are best to the theory (Eq. 3), with as an added parameter (see text). Note that the color and symbol code used in this gure for $_{\rm S}$ corresponds to that used in Fig. 3 for

respectively. Theoretically, the g-factor in our quantum well is predicted to depend substantially on its thickness, and is calculated to be $\mathbf{j}_k \mathbf{j} = 2.8$ and $\mathbf{j}_k \mathbf{j} = 3.5$ for a thickness of 10nm and 15nm, respectively [15]. This agreement with theory gives additional support of our analysis in terms of spin-induced dephasing only, and shows that the measurement of WAL in the presence of an in-plane eld permits to determ ine the in-plane g-factor. Contrary to other methods based on transport measurements, this method to determ ine the g-factor is suitable for disordered systems.

A di erent way to obtain (B_k) (and c), apart from tting the whole (B₂) curves measured at xed B_k, is by looking at the conductance at B₂ = 0 as function of B_k. Speci cally, the theory for spin-induced dephasing predicts that (B₂ = 0;0) (B₂ = 0;B_k) = $\frac{e^2}{h}\ln((0)=(B_k)) = \frac{e^2}{h}\ln(1+cB_k^2)$ [10]. Also in this case, the agreement between theory and data is excellent (Fig. 2, inset) and the thing procedure gives values for the parameter c identical to those obtained above. This shows the consistency of our quantitative analysis and con m s once m ore the validity of the interpretation of the data in term s of spin-induced TRS breaking only.

Finally, Fig. 4 shows the behavior of the measured spin relaxation time as function of B_k for di erent densities and di erent strength of SO I interaction (samples 1 and 2). In all cases, the measured spin relaxation time increases quadratically with increasing the applied in-

plane eld. This directly shows that the presence of an in-plane eld reduces spin-random ization. The increase in $_{\rm s}$ (B_k) is more pronounced for a sm all strength of the SO I interaction and for short values of the elastic scattering time , i.e. for long D yakonov-P erel spin-relaxation times $_{\rm s}$ (0). This is because the Zeem an energy g B_k, that drives the alignment of the electron spin along B_k, competes with the characteristic energy associated to the spin-random ization h= $_{\rm s}$ (0).

A quantitative analysis of the data requires a com parison with theory. For the case of a magnetic ekd norm al to the conduction plane, extensive theoretical analysis exists [16]. For the case of an in-plane ekd, however, only the relaxation time of the z-com ponent of the spin has been calculated as a function of B_k [17]. When the Zeem an energy g B_k is much smaller than $h = {}_{s}(0)$, this quantity is given by

$$\frac{s_{z}(B_{k})}{s_{z}(0)} + \frac{1}{2} (g_{k} B_{k} (0)=h)^{2}$$
(3)

A lthough theoretical predictions for $_{s_x} (B_k)$ and $_{s_y} (B_k)$ are not available, we expect $_{s_x} (B_k) = _{s_x} (0)$ and $_{s_y} (B_k) = _{s_y} (0)$ to exhibit the same functional dependence as $_{s_z} (B_k) = _{s_z} (0)$ as long as $g B_k$ $h = _s (0)$ and kT. This allow sus to compare the measured $_s (B_k) = _s (0)$ to Eq. 3. A llthe quantities that appear in Eq. 3 are known from the previous analysis, and we add a parameter to achieve best ts to the data (theory [17] predicts = 1 in Eq. 3). Figure 4 shows that in all cases good agreement is obtained with '1 (continuous lines). We conclude that the qualitative behavior of the spin-relaxation time as a function of B_k , and (or, equivalently, $_s (0)$) is the one expected, and that, within a sm all correction factor, our results are in quantitative agreement with theoretical predictions.

In view of the quantitative agreem ent between theory and data obtained throughout this work, it is worth considering the origin of the sm all correction factor . € 1 m ay originate from the lim ited accuracy with which the quantities in Eq. 3 are determ ined. The largest uncertainty comes from g_k and is approximately 10%. An additional possibility is the B_k -induced an isotropy of the inplane spin relaxation times, i.e. B_k breaks spin-rotational symmetry in the 2D plane. A lihough this anisotropy is expected to be small for $g_k = B_k = h = s(0)$ and $k_B T$, as mentioned before, it may result in a deviation from = 1. Finally, for sample 1 with the weakest R ashba SO I, the D resselhaus term may not be entirely negligible [18].

In conclusion, we have observed how the partial alignm ent of the electron spin along an applied in-plane m agnetic eld determ ines the orbital and spin dynam ics of electrons in R ashba 2D EG s. This alignm ent results in a spin-induced time reversal symmetry breaking and in a quadratic increase of the spin-relaxation time. The detailed quantitative analysis of our results demonstrates the validity of the existing theory and gives indications to its limits.

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